

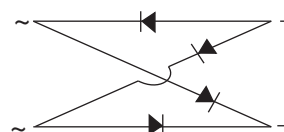
Features

- Idea for printed circuit board
- Glass passivated junction chip
- High forward surge current capability
- High temperature soldering:
260°C/10 seconds at terminals
- Component in accordance to
RoHS 2011/65/EU



RoHS
COMPLIANT

DB-S



Mechanical Data

- **Case:**DB-S
Epoxy meets UL 94 V-0 flammability rating
- **Terminals:**Plated leads, solderable per
MIL-STD-750, Method 2026
- **Polarity:** Polarity symbols marked on body
- **Mounting Position:** Any

Maximum Ratings & Thermal Characteristics (T_A = 25 °C unless otherwise noted)

Parameter	Symbol	DB 151S	DB 152S	DB 153S	DB 154S	DB 155S	DB 156S	DB 157S	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS reverse voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maverage rectified output current @T _L =105°C	I _{F(AV)}	1.5							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	50							A
Typical thermal resistance from junction to Lead ⁽¹⁾	R _{θJL}	15							°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150							°C

Electrical Characteristics (T_A = 25 °C unless otherwise noted)

Parameter		Symbol	DB 151S	DB 152S	DB 153S	DB 154S	DB 155S	DB 156S	DB 157S	Unit
Maximum instantaneous forward voltage at 1.5A		V _F	1.1							V
Maximum DC reverse current at rated DC blocking voltage per leg	T _A =25℃	I _R	5.0							μA
	T _A =125℃		500							
Typical junction capacitance ⁽²⁾		C _J	25							pF

Note:1.Units mounted on PCB with 0.51" x 0.51" (13 mm x 13 mm) copper pads

2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

Characteristic Curves $T_A=25\text{ }^{\circ}\text{C}$ unless otherwise noted

Fig. 1 - Derating Curve Output Rectified Current

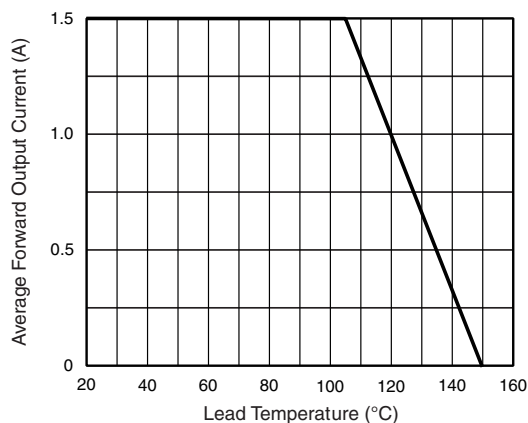


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

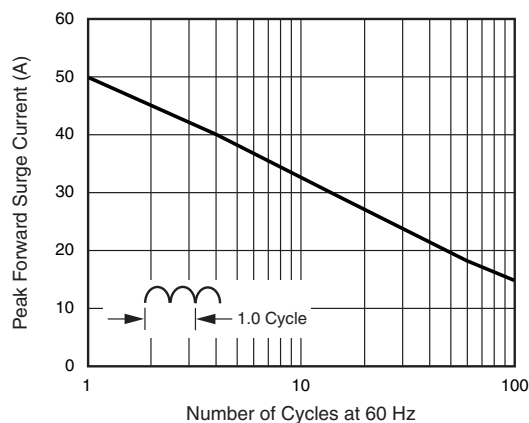


Fig. 3 - Typical Forward Characteristics Per Diode

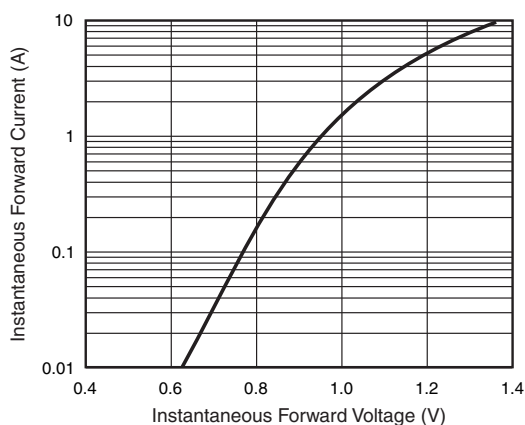
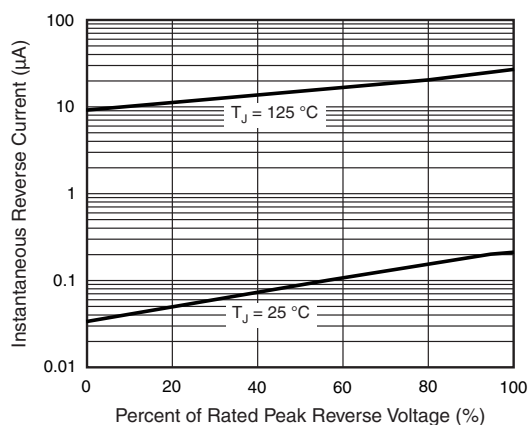
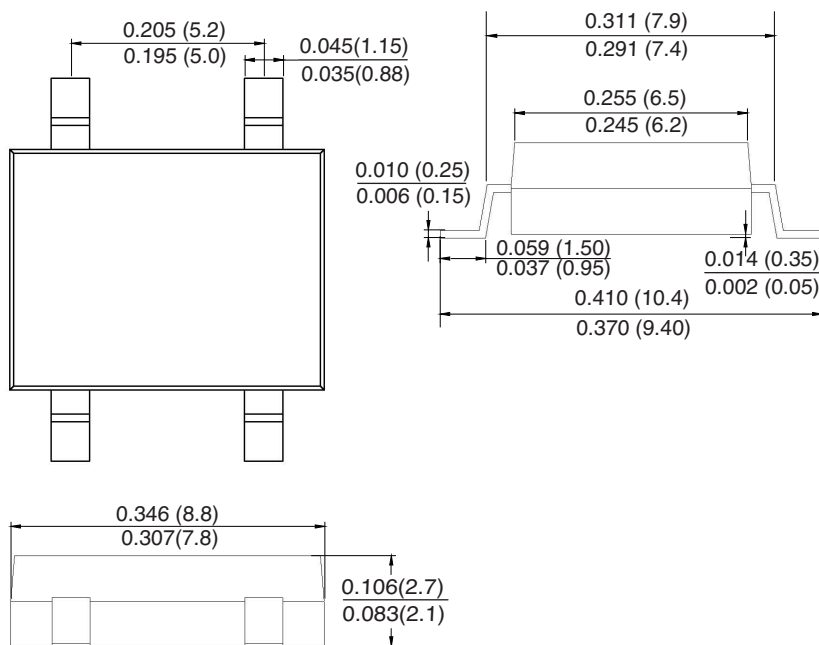


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

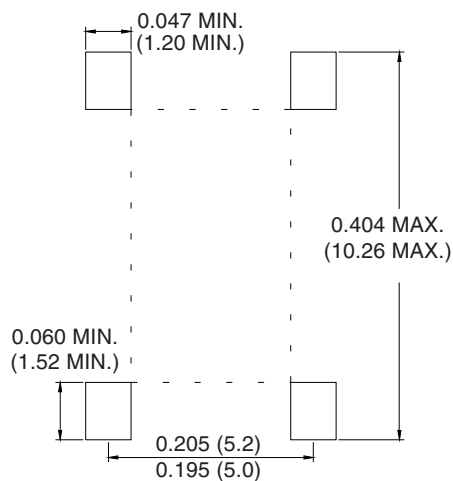


Package Outline

DB-S



Mounting Pad Layout



Dimensions in inches and (millimeters)

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